## OP168F, OP169, OP268F, OP269 Series



#### Features:

- Flat lens for wide radiation angle (OP168, OP268)
- Integral lens for narrow beam angle (OP169, OP269)
- Easily stackable on 0.100" (2.54 mm) hole centers
- Mechanically and spectrally matched to other OPTEK devices



#### **Description:**

Each diode in this series is molded into an end-looking plastic package. The package for all **OP168F** and **OP268F** devices is black, whereas the package for all **OP169** and **OP269** packages is clear. **OP168F** and **OP169** devices are GaAs. **OP268F** and **OP269** devices are GaAlAs.

Due to their small size, all diodes in this series offer considerable design flexibility.

The OP168F and OP268F series are mechanically and spectrally matched to the OP508F series phototransistor and the OP538F series photodarlingtons. The OP169 and OP269 series are mechanically and spectrally matched to the OP509 series phototransistors.

Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

For custom screening contact your OPTEK representative.

### **Applications:**

- Space-limited applications
- · Excellent design flexibility
- · PCBoard mounted slotted switch
- PCBoard interrupter

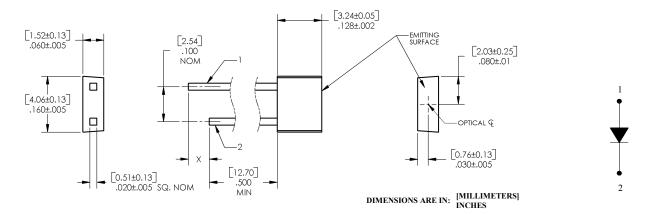
Ordering Information						
Part Number	LED Peak Wavelength	Total Beam Angle	Lead Length			
OP168FA	935 nm	104°	0.50"			
OP168FB	935 11111	104				
OP169B	935 nm	18°				
OP169C	955 1111	10				
OP268FA						
OP268FB	890 nm	104°				
OP268FC						
OP269A	890 nm	18"				



OP168F, OP169, OP268F, OP269 Series

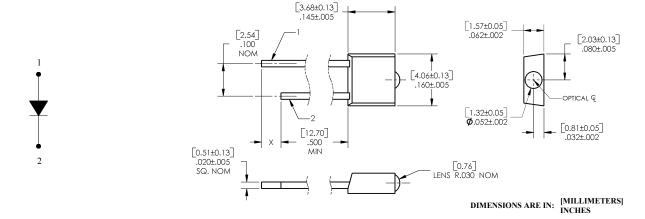


#### OP168F (B, C), OP268F (A)



Pin #	LED X=0.060" (1.5 mm)		
1	Anode		
2	Cathode		

### OP169 (A, B, C), OP269 (A, B, C)



Pin #	LED X=0.060" (1.5 mm)			
1	Anode			
2	Cathode			

OP168F, OP169, OP268F, OP269 Series



## **Electrical Specifications**

Absolute Maximum Ratings (T <sub>A</sub> = 25° C unless otherwise noted)				
Storage and Operating Temperature Range	-40° C to +100° C			
Reverse Voltage	2.0 V			
Continuous Forward Current	50 mA			
Peak Forward Current (1 μs pulse width, 300 pps) OP168, OP169, OP268, OP269 (A)	3.0 A			
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron] <sup>(1)</sup>	260° C			
Power Dissipation <sup>(2)</sup>	100 mW			

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
nput Diode	•						
	Apertured Radiant Incidence						
	OP168FA	0.48	-	0.73	mW/cm²	I <sub>F</sub> = 20 mA Aperture = .081" dia. Distance = .400" from tip of lens to aperture surface	
	OP168FB	0.43	-	-			
E <sub>E (APT)</sub> <sup>(3)</sup>	OP169B	0.11	-	0.22			
	OP169C	0.03	-	-			
			-				
	OP268FA	0.64	-	-			
	OP268FB	0.45	-	0.99			
	OP268FC	0.36	-	-			
	OP269A	0.58	-	-			
	Forward Voltage						
$V_{F}$	OP168, OP169	_	-	1.40	V	I <sub>F</sub> = 20 mA	
-1	OP268, OP269	-	-	1.50		•	
1	Reverse Current						
I <sub>R</sub>	OP168, OP169, OP268, OP269	-	-	100	μΑ	V <sub>R</sub> = 2.0 V	
$\lambda_{ extsf{P}}$	Wavelength at Peak Emission						
	OP168, OP169	-	935	-	nm	I <sub>F</sub> = 20 mA	
	OP268, OP269	-	890	-	'''''	IF - 20 IIIA	

#### Notes:

- 1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.
- 2. Derate linearly 1.33 mW/° C above 25° C.
- 3. For OP168 (FB, FC) and OP268 (FA, FB, FC), E<sub>E(APT)</sub> is a measurement of the average apertured radiant energy incident upon a sensing area 0.081" (2.06 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.400" (10.16 mm) from the measurement surface. For OP169 (B, C) and OP269 (A), E<sub>E(APT)</sub> is a measurement of the average apertured radiant energy incident upon a sensing area 0.180" (4.57 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.653" (16.6 mm) from the lens tip. NOTE: E<sub>E(APT)</sub> is a measurement of the *average* radiant intensity within the cone formed by the above conditions. E<sub>E(APT)</sub> is not necessarily uniform within the measured area.

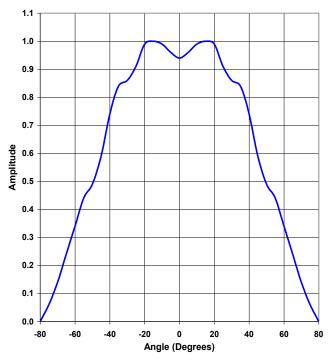
OP168F, OP169, OP268F, OP269 Series



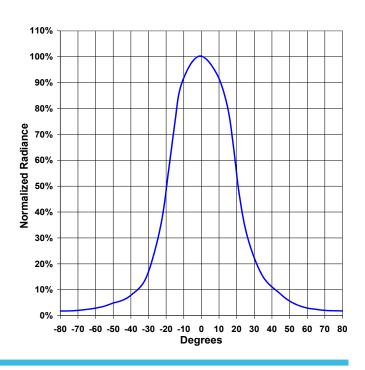
## Electrical Characteristics (T<sub>A</sub> = 25° C unless otherwise noted — for reference only)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
В	Spectral Bandwidth between Half Power Points OP168, OP169 OP268, OP269	-	50 80	-	nm	I <sub>F</sub> = 10 mA
$\Delta \lambda_{\scriptscriptstyle P}/\Delta T$	Spectral Shift with Temperature OP168, OP169 OP268, OP269		±0.30 ±0.18	-	nm/°C	I <sub>F</sub> = Constant
$\theta_{\sf HP}$	Emission Angle at Half Power Points OP168 OP169 OP268 OP269		104° 46° 104° 46°		Degree	I <sub>F</sub> = 20 mA
t <sub>r</sub>	Rise Time OP168, OP169 OP268, OP269	- - -	1000 500 10	- - -	ns	I <sub>F(PK)</sub> =100 mA, PW=10 μs, D.C.=10%
t <sub>f</sub>	Fall Time OP168, OP169 OP268, OP269		500 250 10		ns	I <sub>F(PK)</sub> =100 mA, PW=10 μs, D.C.=10%

### Beam Angle OP168 & OP268 Package



#### Beam Angle OP169 & OP269 Package

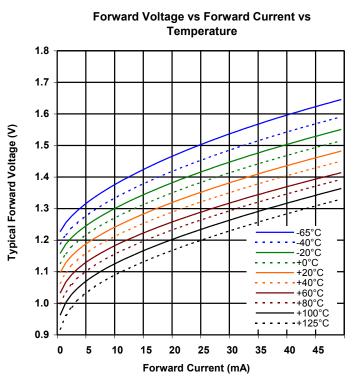


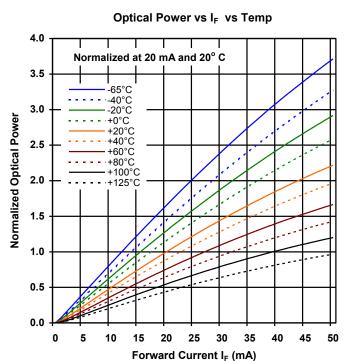
OP168F, OP169, OP268F, OP269 Series



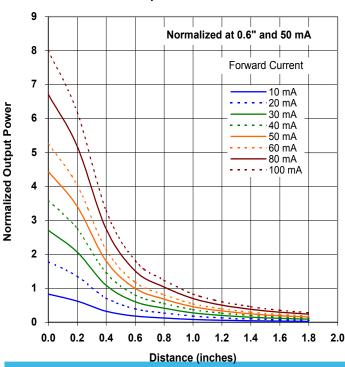
### **Performance**

OP168 (FB, FC), OP169 (B, C)





#### **Distance vs Output Power vs Forward Current**



General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

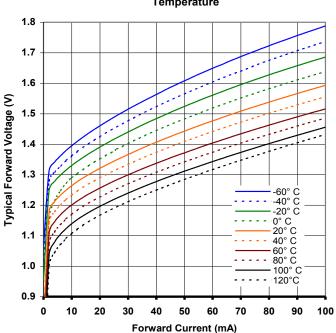
OP168F, OP169, OP268F, OP269 Series



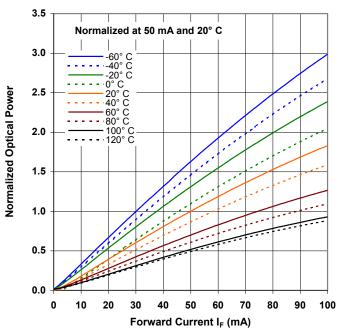
### **Performance**

OP268 (FA, FB, FC), OP269 (A)

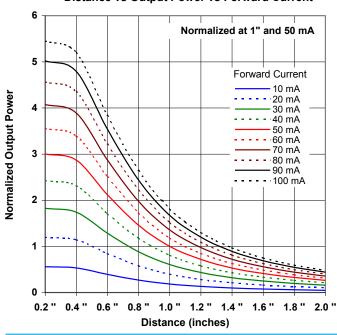
#### Forward Voltage vs Forward Current vs Temperature



### Optical Power vs I<sub>F</sub> vs Temperature



#### **Distance vs Output Power vs Forward Current**



## **Mouser Electronics**

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## TT Electronics:

<u>OP168FA</u> <u>OP168FB</u> <u>OP168FC</u> <u>OP169A</u> <u>OP169B</u> <u>OP169C</u> <u>OP268FA</u> <u>OP268FB</u> <u>OP268FC</u> <u>OP268FPS</u> OP269A OP269B OP269C